

Rectifier Diode

Types W1360LG240 to W1360LG300

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	2400-3000	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	2500-3100	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=55^{\circ}C$, (note 2)	1360	A
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=100^{\circ}C$, (note 2)	940	A
$I_{F(AV)M}$	Maximum average forward current, $T_{sink}=100^{\circ}C$, (note 3)	520	A
$I_{F(RMS)M}$	Nominal RMS forward current, $T_{sink}=25^{\circ}C$, (note 2)	2510	A
$I_{F(d.c.)}$	D.C. forward current, $T_{sink}=25^{\circ}C$, (note 4)	2180	A
I_{FSM}	Peak non-repetitive surge $t_p=10ms$, $V_{rm}=60\%V_{RRM}$, (note 5)	12.7	kA
I_{FSM2}	Peak non-repetitive surge $t_p=10ms$, $V_{rm}\leq 10V$, (note 5)	14.6	kA
I^2t	I^2t capacity for fusing $t_p=10ms$, $V_{rm}=60\%V_{RRM}$, (note 5)	0.8×10^6	A^2s
I^2t	I^2t capacity for fusing $t_p=10ms$, $V_{rm}\leq 10V$, (note 5)	1.07×10^6	A^2s
$T_{j op}$	Operating temperature range	-30 to +160	$^{\circ}C$
T_{stg}	Storage temperature range	-40 to +185	$^{\circ}C$

Notes:-

- 1) De-rating factor of 0.13% per $^{\circ}C$ is applicable for T_j below $25^{\circ}C$.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Cathode side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, $160^{\circ}C$ T_j initial.

Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{FM}	Maximum peak forward voltage	-	-	1.87	I _{FM} =3090A	V
V _{T0}	Threshold voltage	-	-	0.87		V
r _T	Slope resistance	-	-	0.323		mΩ
I _{RRM}	Peak reverse current	-	-	30	Rated V _{RRM}	mA
R _{thJK}	Thermal resistance, junction to heatsink	-	-	0.0394	Double side cooled	K/W
		-	-	0.0707	Anode side cooled	K/W
		-	-	0.0898	Cathode side cooled	K/W
F	Mounting force	10	-	20	Note 2	kN
W _t	Weight		400			g

Notes:-

- 1) Unless otherwise indicated T_j=160°C.
- 2) For other clamp forces, please consult factory.

Notes on Ratings and Characteristics

1.0 Voltage Grade Table

Voltage Grade	V_{RRM} V	V_{RSM} V	V_R DC V
24	2400	2500	1450
30	3000	3100	1750

2.0 Extension of Voltage Grades

This report is applicable to other voltage grades when supply has been agreed by Sales/Production.

3.0 De-rating Factor

A blocking voltage de-rating factor of 0.13%/°C is applicable to this device for T_j below 25°C.

4.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

5.0 Computer Modelling Parameters

5.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_{T0} + \sqrt{V_{T0}^2 + 4 \cdot ff^2 \cdot r_T \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_T}$$

and:

$$W_{AV} = \frac{\Delta T}{R_{th}}$$

$$\Delta T = T_{jmax} - T_K$$

Where $V_{T0}=0.87V$, $r_T=0.323m\Omega$,

R_{th} = Supplementary thermal impedance, see table below and

ff = Form factor, see table below.

Supplementary Thermal Impedance				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave Double Side Cooled	0.0480	0.0445	0.0425	0.03940
Square wave Anode Side Cooled	0.0797	0.0759	0.0738	0.0707
Square wave Cathode Side Cooled	0.0983	0.0950	0.0929	0.0898
Sine wave Double Side Cooled	0.0451	0.0422	0.0396	
Sine wave Anode Side Cooled	0.0762	0.0732	0.0707	
Sine wave Cathode Side Cooled	0.0957	0.0928	0.0901	

Form Factors				
Conduction Angle	6 phase (60°)	3 phase (120°)	½ wave (180°)	d.c.
Square wave	2.449	1.732	1.414	1
Sine wave	2.778	1.879	1.57	

5.2 Calculating V_F using ABCD Coefficients

The on-state characteristic I_F vs. V_F , on page 6 is represented in two ways;

- the well established V_{T0} and r_T tangent used for rating purposes and
- a set of constants A, B, C, D, forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given below for both hot and cold characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

160°C Coefficients	
A	-0.01007431
B	0.1902643
C	4.26144×10^{-4}
D	-0.01710505

5.3 D.C. Thermal Impedance Calculation

$$r_t = \sum_{p=1}^{p=n} r_p \cdot \left(1 - e^{\frac{-t}{\tau_p}} \right)$$

Where $p = 1$ to n , n is the number of terms in the series and:

- t = Duration of heating pulse in seconds.
- r_t = Thermal resistance at time t .
- r_p = Amplitude of p th term.
- τ_p = Time Constant of r th term.

The coefficients for this device are shown in the tables below:

D.C. Double Side Cooled				
Term	1	2	3	4
r_p	0.02350677	0.01080067	3.111832×10^{-3}	1.946426×10^{-3}
τ_p	1.261361	0.1407335	0.01999451	2.677464×10^{-3}

D.C. Anode Side Cooled					
Term	1	2	3	4	5
r_p	0.04517370	0.01092023	0.01002468	2.972535×10^{-3}	1.644544×10^{-3}
τ_p	6.555359	0.7723341	0.1155237	0.01578855	2.018220×10^{-3}

D.C. Cathode Side Cooled				
Term	1	2	3	4
r_p	0.06840358	0.01444154	4.487340×10^{-3}	2.389196×10^{-3}
τ_p	7.458694	0.2510212	0.03334104	3.271107×10^{-3}

Curves

Figure 1 – Forward characteristics of Limit device

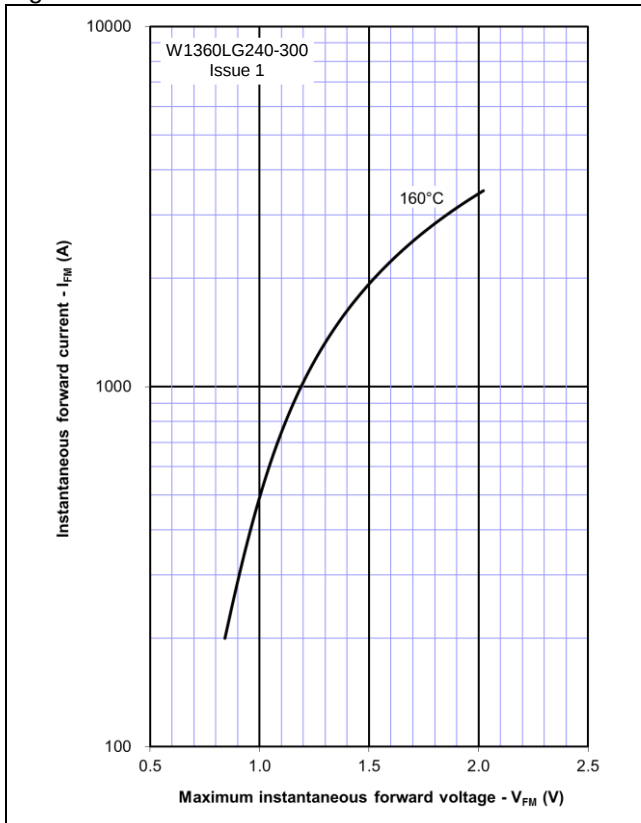


Figure 2 – Transient thermal impedance

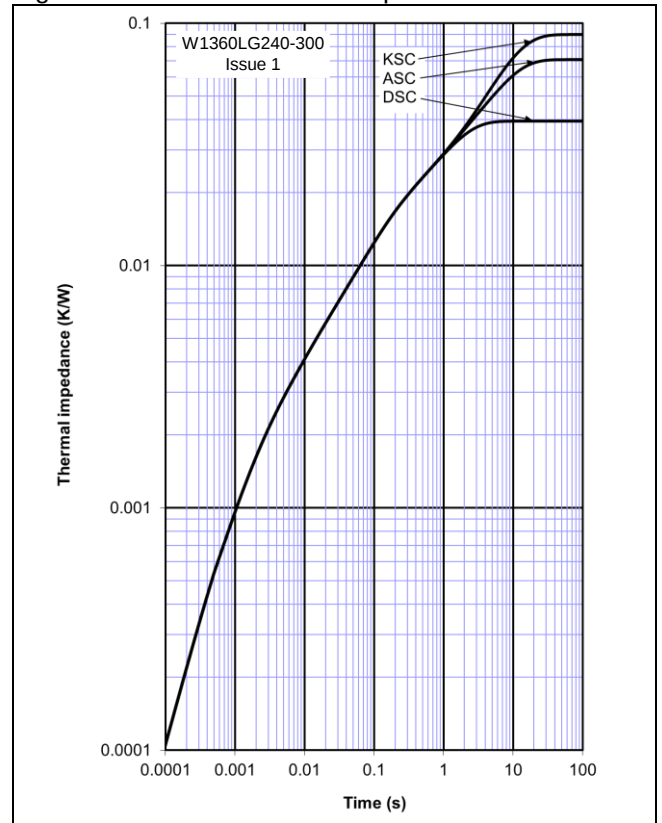


Figure 3 – Maximum Surge Rating

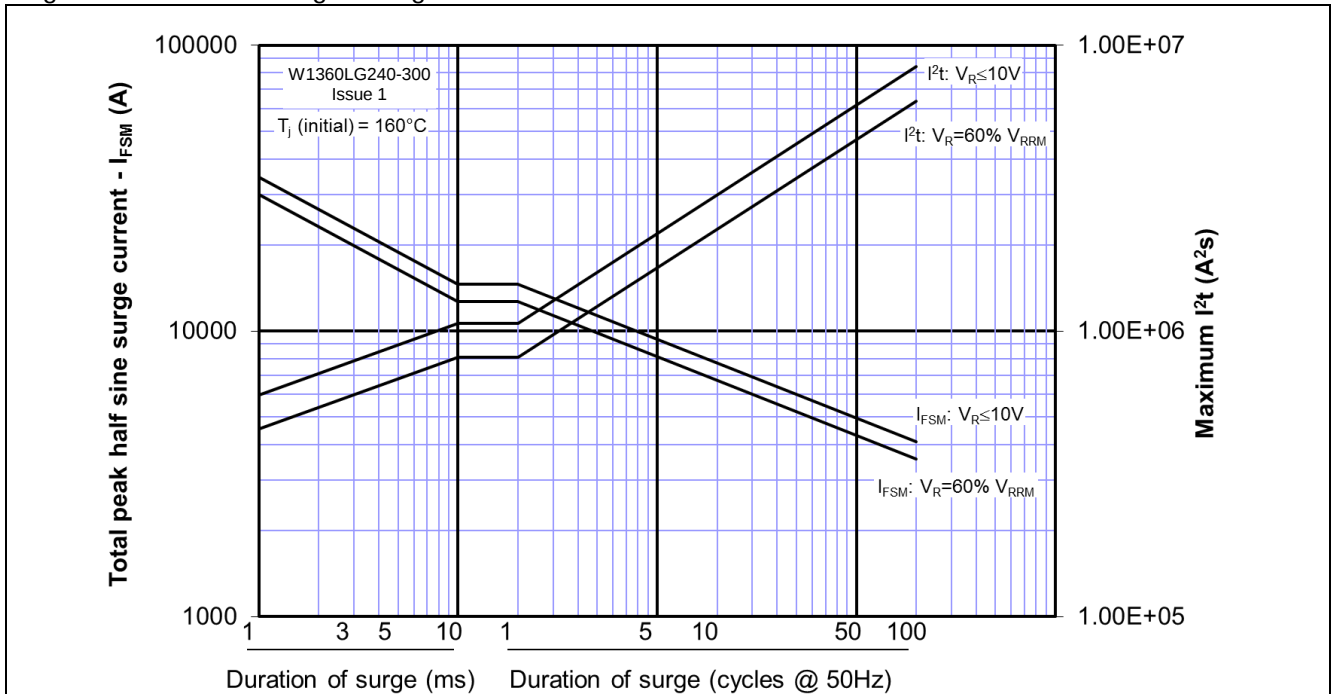


Figure 4 – Forward current vs. Power dissipation – Double Side Cooled

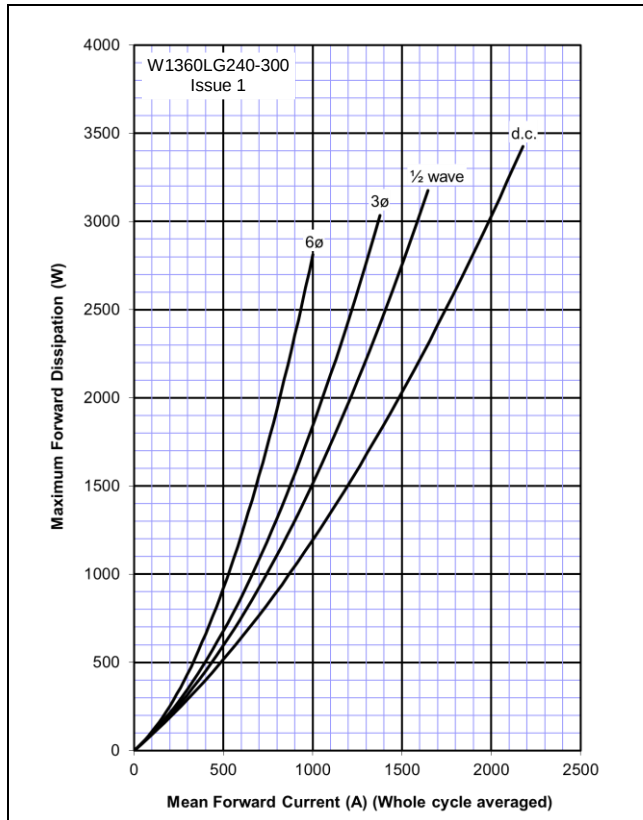


Figure 5 – Forward current vs. Heatsink temperature – Double Side Cooled

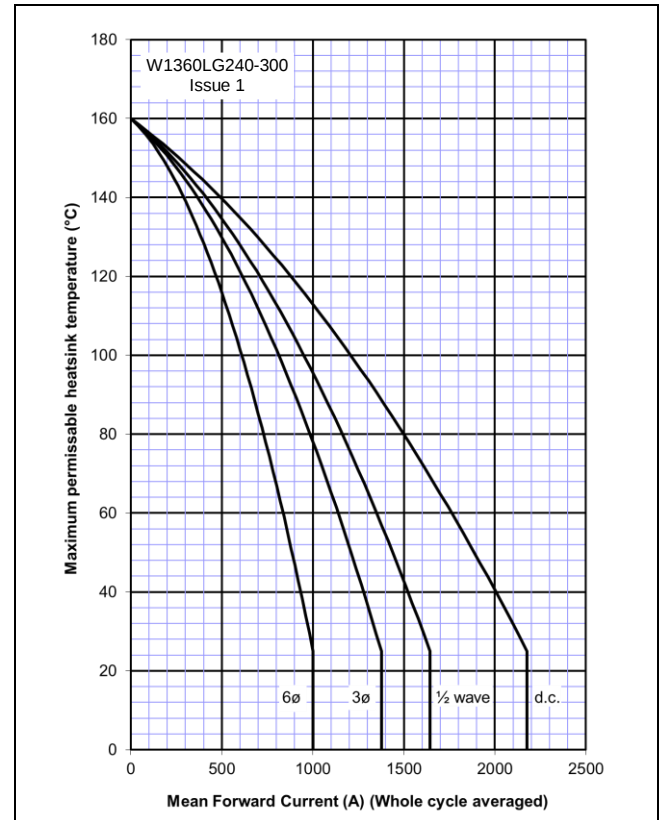


Figure 6 – Forward current vs. Power dissipation – Cathode Side Cooled

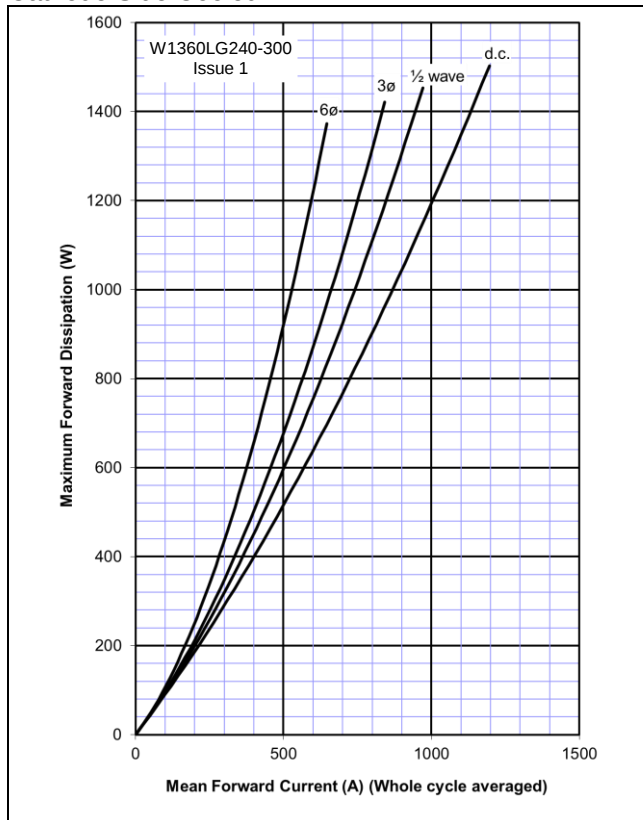
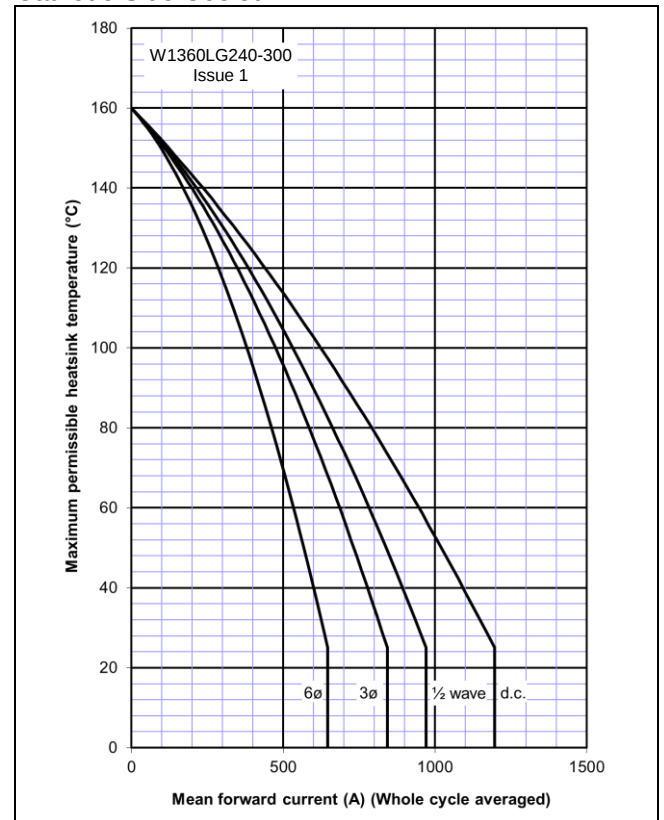
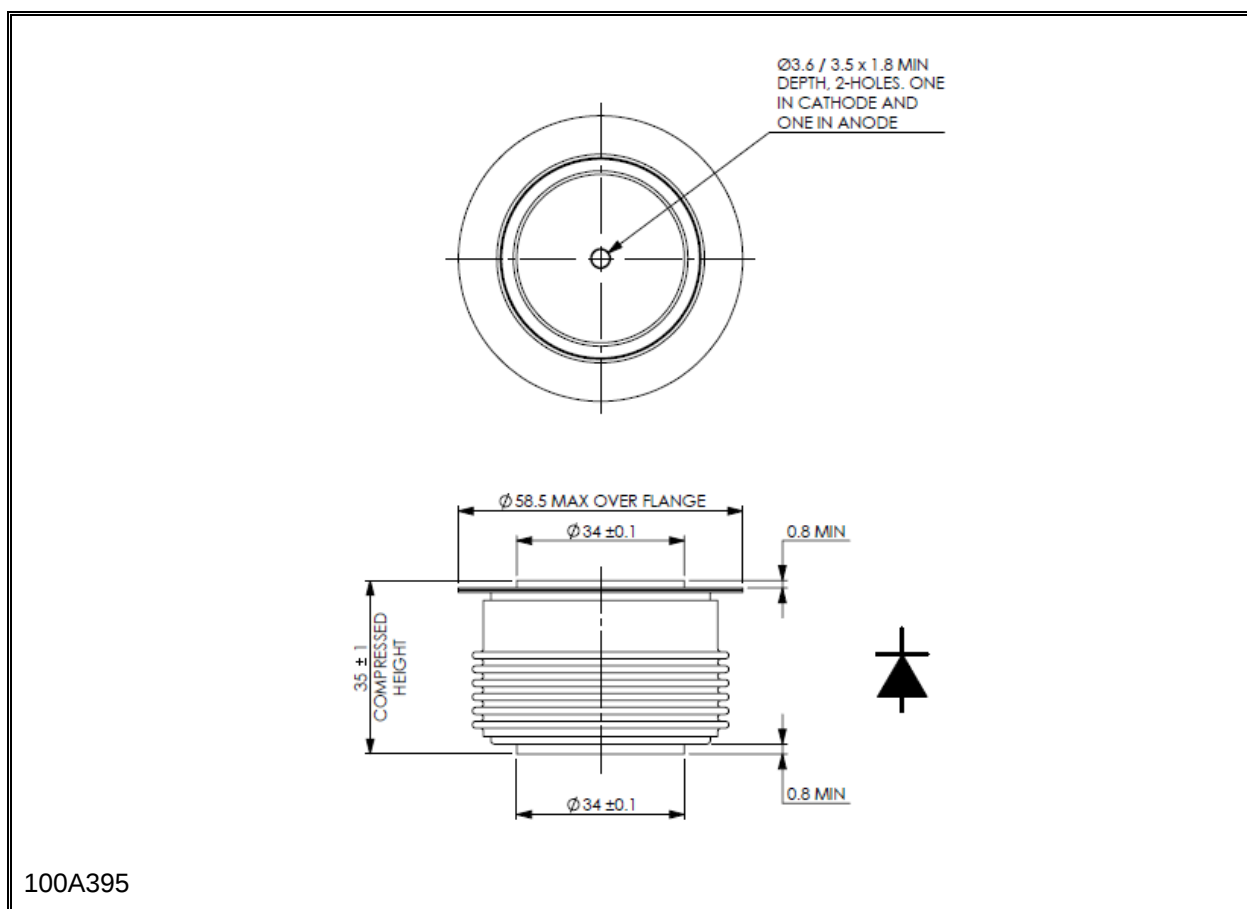


Figure 7 – Forward current vs. Heatsink temperature – Cathode Side Cooled



Outline Drawing & Ordering Information



ORDERING INFORMATION		(Please quote 10 digit code as below)	
W1360	LG	◆◆	0
Fixed Type Code	Fixed Outline Code	Voltage code V _{RRM} /100 24 & 30	Fixed code
Order code: W1360LG300 – 3000V V _{RRM} , 35mm clamp height capsule.			
IXYS Semiconductor GmbH Edisonstraße 15 D-68623 Lampertheim Tel: +49 6206 503-0 Fax: +49 6206 503-627 E-mail: marcom@ixys.de		 IXYS UK Westcode Ltd Langley Park Way, Langley Park, Chippenham, Wiltshire, SN15 1GE. Tel: +44 (0)1249 444524 Fax: +44 (0)1249 659448 E-mail: sales@ixysuk.com	
IXYS Corporation 1590 Buckeye Drive Milpitas CA 95035-7418 Tel: +1 (408) 457 9000 Fax: +1 (408) 496 0670 E-mail: sales@ixys.net		www.ixysuk.com www.ixys.com	
		IXYS Long Beach IXYS Long Beach, Inc 2500 Mira Mar Ave, Long Beach CA 90815 Tel: +1 (562) 296 6584 Fax: +1 (562) 296 6585 E-mail: service@ixyslongbeach.com	
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